NSN 5961-01-096-7851

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View Online at https://aerobasegroup.com/nsn/5961-01-096-7851 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.800 inches **Overall Height:** 0.225 inches **Overall Width:** Between 0.405 inches and 0.425 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 3.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 14.00 amperes source cutoff current **Power Rating Per Characteristic:** 115.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 06845-4042879 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ribbon and 1 case **Specification Data:** 06845-4043763 manufacturers specification Shelf Life: N/a **Unit Of Measure:**

A110a0

No Fiig:

Demilitarization: